Battery Management Unit Impedance Track™ Fuel Gauge for Use With the bq2416x Charger Controller

Check for Samples: bq27530-G1

FEATURES

- **Battery Fuel Gauge and Charger Controller for 1-Series Li-Ion Applications**
- **Resides on System Main Board**
- **Battery Fuel Gauge Based on Patented Impedance Track™ Technology**
  - **Models the Battery Discharge Curve for Accurate Time-to-Empty Predictions**
  - **Automatically Adjusts for Battery Aging, Battery Self-Discharge, and Temperature/Rate Inefficiencies**
  - **Low-Value Sense Resistor (5 mΩ to 20 mΩ)**
- **Battery Charger Controller with customizable charge profiles**
  - **Configurable Charge Voltage and Current based on Temperature**
  - **Optional State of Health (SoH) and Multi-level based charge profiles**
- **Host Free Autonomous Battery Management System**
  - **Reduced software overhead allows for easy portability across platforms and shorter OEM design cycles**
  - **Higher safety and security**
- **Run Time Improvements**
  - **Longer battery runtime leveraging Impedance Track technoloogy**
  - **Tighter accuracy controls for charger termination**
  - **Improved recharged thresholds**
- **Intelligent Charging - Customized and adaptive charging profiles**
  - **Charger Control based on SoH**
  - **Temperature Level Charging (TLC)**
- **Battery Charger Controller for bq2416x Single Cell Switchmode Battery Charger**
  - **Stand-Alone Charging Solution**
- **400-kHz I^2C™ Interface for Connection to System Microcontroller Port**
- **In a 15-Pin NanoFree™ (CSP) Packaging**

APPLICATIONS

- **Smartphones, Feature phones and Tablets**
- **Digital Still and Video Cameras**
- **Handheld Terminals**
- **MP3 or Multimedia Players**

DESCRIPTION

The Texas Instruments bq27530-G1 system-side Li-Ion Battery Management Unit is a microcontroller peripheral that provides Impedance Track™ fuel gauging and charging control for single-cell Li-Ion battery packs. The device requires little system microcontroller firmware development. Together with bq2416x Single Cell Switchmode Charger, the bq27530-G1 manages an embedded battery (non-removable) or a removable battery pack.

The bq27530-G1 uses the patented Impedance Track™ algorithm for fuel gauging, and provides information such as remaining battery capacity (mAh), state-of-charge (%), run-time to empty (min), battery voltage (mV), temperature (°C) and state of health (%).

Battery fuel gauging with the bq27530-G1 requires only PACK+ (P+), PACK– (P–), and Thermistor (T) connections to a removable battery pack or embedded battery circuit. The CSP option is a 15-ball package in the dimensions of 2,61 mm × 1,96 mm with 0,5 mm lead pitch. It is ideal for space constrained applications.

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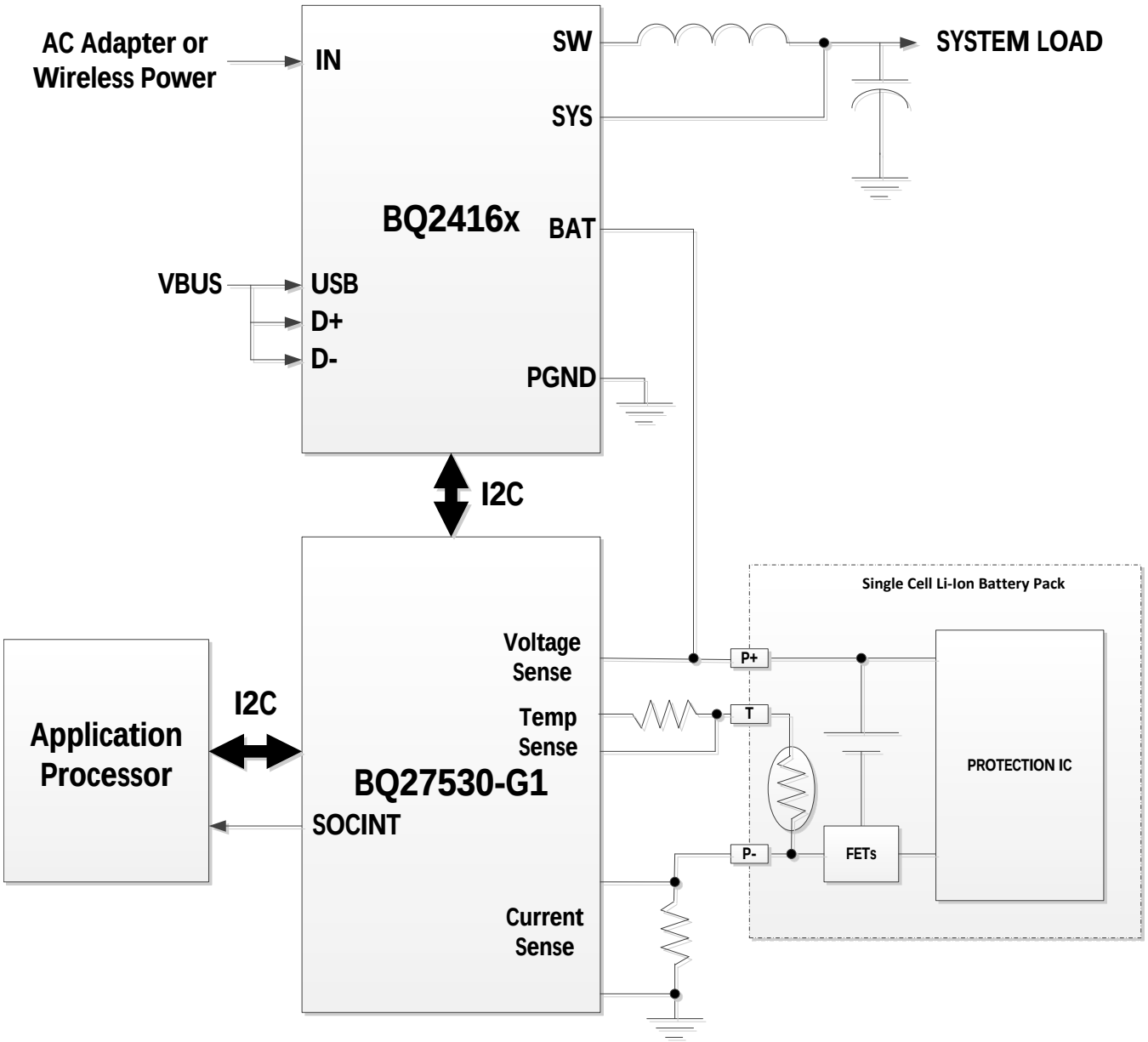
These devices have limited built-in ESD protection. The leads should be shorted together or



DEVICE INFORMATION

AVAILABLE OPTIONS

PART NUMBER	FIRMWARE VERSION(1)	PACKAGE(2)	T_A	COMMUNICATION FORMAT	TAPE and REEL QUANTITY
bq27530YZFR-G1	1.04 (0x0104)	CSP-15	–40°C to 85°C	I^2C	3000
bq27530YZFT-G1					250

(1) Refer to the *FW_VERSION* subcommand to confirm the firmware version.
(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

THERMAL INFORMATION

THERMAL METRIC(1)		bq27530-G1 YZF(15 PINS)	UNITS
θ_{JA}	Junction-to-ambient thermal resistance	70	°C/W
θ_{JCtop}	Junction-to-case (top) thermal resistance	17	
θ_{JB}	Junction-to-board thermal resistance	20	
ψ_{JT}	Junction-to-top characterization parameter	1	
ψ_{JB}	Junction-to-board characterization parameter	18	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance	n/a	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953

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PIN ASSIGNMENT AND PACKAGE DIMENSIONS

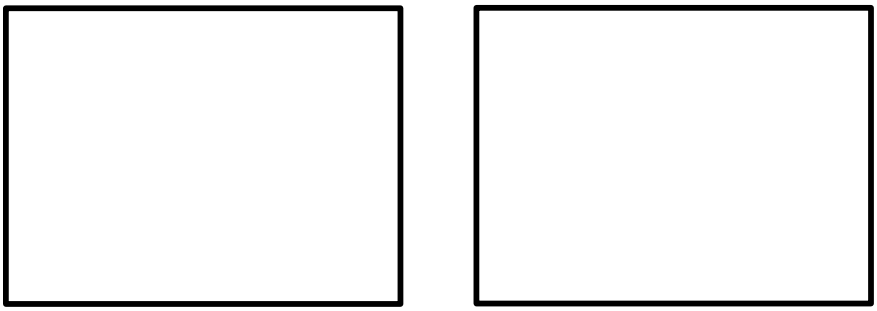

Table 1. PIN FUNCTIONS

PIN		TYPE(1)	DESCRIPTION
NAME	NO.		
SRP	A1	IA	Analog input pin connected to the internal coulomb counter where SRP is nearest the PACK– connection. Connect to 5-mΩ to 20-mΩ sense resistor.
SRN	B1	IA	Analog input pin connected to the internal coulomb counter where SRN is nearest the Vss connection. Connect to 5-mΩ to 20-mΩ sense resistor.
V_{SS}	C1, C2	P	Device ground
V_{CC}	D1	P	Regulator output and bq27530-G1 power. Decouple with 1µF ceramic capacitor to Vss.
REGIN	E1	P	Regulator input. Decouple with 0.1µF ceramic capacitor to Vss.
SOC_INT	A2	I/O	SOC state interrupts output. Generates a pulse as described in *bq27530-G1 Technical Reference Manual*. Open drain output.
BSCL	B2	O	Battery Charger clock output line for chipset communication. Push-pull output. **Note:** CE has an internal ESD protection diode connected to REGIN. Recommend maintaining $V_{CE} \le V_{REGIN}$ under all conditions.
CE	D2	I	Chip Enable. Internal LDO is disconnected from REGIN when driven low.
BAT	E2	I	Cell-voltage measurement input. ADC input. Recommend 4.8V maximum for conversion accuracy.
SCL	A3	I	Slave I^2C serial communications clock input line for communication with system (Master). Open-drain I/O. Use with 10kΩ pull-up resistor (typical).
SDA	B3	I/O	Slave I^2C serial communications data line for communication with system (Master). Open-drain I/O. Use with 10kΩ pull-up resistor (typical).
BSDA	C3	I/O	Battery Charger data line for chipset communication. Push-pull output.
TS	D3	IA	Pack thermistor voltage sense (use 103AT-type thermistor). ADC input.
BI/TOUT	E3	I/O	Battery-insertion detection input. Power pin for pack thermistor network. Thermistor-multiplexer control pin. Use with pull-up resistor >1MΩ (1.8 MΩ typical).

(1) I/O = Digital input/output, IA = Analog input, P = Power connection

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ELECTRICAL SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)(1)

PARAMETER		VALUE	UNIT
V_{REGIN}	Regulator input range	–0.3 to 5.5	V
		–0.3 to 6.0 (2)	V
V_{CE}	CE input pin	–0.3 to V_{REGIN} + 0.3	V
V_{CC}	Supply voltage range	–0.3 to 2.75	V
V_{IOD}	Open-drain I/O pins (SDA, SCL, SOC_INT)	–0.3 to 5.5	V
V_{BAT}	BAT input pin	–0.3 to 5.5	V
		–0.3 to 6.0 (2)	V
V_I	Input voltage range to all other pins (BI/TOUT, TS, SRP, SRN, BSDA, BSCL)	–0.3 to V_{CC} + 0.3	V
ESD	Human-body model (HBM), BAT pin	1.5	kV
	Human-body model (HBM), all other pins	2	
T_A	Operating free-air temperature range	–40 to 85	°C
T_{stg}	Storage temperature range	–65 to 150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings

ADC (TEMPERATURE AND CELL MEASUREMENT) CHARACTERISTICS

T_A = –40°C to 85°C, 2.4 V < V_{CC} < 2.6 V; typical values at T_A = 25°C and V_{CC} = 2.5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{ADC1}	Input voltage range (TS)		V_{SS} – 0.125		2	V
V_{ADC2}	Input voltage range (BAT)		V_{SS} – 0.125		5	V
$V_{IN(ADC)}$	Input voltage range		0.05		1	V
G_{TEMP}	Internal temperature sensor voltage gain			–2		mV/°C
t_{ADC_CONV}	Conversion time				125	ms
	Resolution		14		15	bits
$V_{OS(ADC)}$	Input offset			1		mV
Z_{ADC1} (1)	Effective input resistance (TS)		8			MΩ
Z_{ADC2} (1)	Effective input resistance (BAT)	bq27530-G1 not measuring cell voltage	8			MΩ
		bq27530-G1 measuring cell voltage		100		kΩ
$I_{lkg(ADC)}$ (1)	Input leakage current				0.3	μA

(1) Specified by design. Not tested in production.

INTEGRATING ADC (COULOMB COUNTER) CHARACTERISTICS

T_A = –40°C to 85°C, 2.4 V < V_{CC} < 2.6 V; typical values at T_A = 25°C and V_{CC} = 2.5 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{SR}	Input voltage range, $V_{(SRP)}$ and $V_{(SRN)}$	V_{SR} = $V_{(SRP)}$ – $V_{(SRN)}$	–0.125		0.125	V
t_{SR_CONV}	Conversion time	Single conversion		1		s
	Resolution		14		15	bits
$V_{OS(SR)}$	Input offset SR)			10		μV
INL	Integral nonlinearity error			±0.007	±0.034	

GENERAL DESCRIPTION

The bq27530-G1 accurately predicts the battery capacity and other operational characteristics of a single Li-based rechargeable cell. It can be interrogated by a system processor to provide cell information, such as time-to-empty (TTE), and state-of-charge (SOC) as well as SOC interrupt signal to the host.

The bq27530-G1 can control a bq2416x Charger IC without the intervention from an application system processor. Using the bq27530-G1 and bq2416x chipset, batteries can be charged with the typical constant-current, constant voltage (CCCV) profile or charged using a Multi-Level Charging (MLC) algorithm.

Information is accessed through a series of commands, called *Standard Commands*. Further capabilities are provided by the additional *Extended Commands* set. Both sets of commands, indicated by the general format *Command( )*, are used to read and write information contained within the device control and status registers, as well as its data flash locations. Commands are sent from system to gauge using the bq27530-G1's I^2C serial communications engine, and can be executed during application development, pack manufacture, or end-equipment operation.

Cell information is stored in the device in non-volatile flash memory. Many of these data flash locations are accessible during application development. They cannot, generally, be accessed directly during end-equipment operation. Access to these locations is achieved by either use of the bq27530-G1's companion evaluation software, through individual commands, or through a sequence of data-flash-access commands. To access a desired data flash location, the correct data flash subclass and offset must be known.

The key to the bq27530-G1 high-accuracy gas gauging prediction is Texas Instrument's proprietary Impedance Track™ algorithm. This algorithm uses cell measurements, characteristics, and properties to create state-of-charge predictions that can achieve less than 1% error across a wide variety of operating conditions and over the lifetime of the battery.

The device measures battery charge/discharge activity by monitoring the voltage across a small-value series sense resistor (5 mΩ to 20 mΩ typ.) located between the system's Vss and the battery's PACK- terminal. When a cell is attached to the device, cell impedance is computed, based on cell current, cell open-circuit voltage (OCV), and cell voltage under loading conditions.

The device external temperature sensing is optimized with the use of a high accuracy negative temperature coefficient (NTC) thermistor with R25 = 10.0kΩ ±1%, B25/85 = 3435K ± 1% (such as Semitec NTC 103AT). The bq27530-G1 can also be configured to use its internal temperature sensor. When an external thermistor is used, a 18.2k pull up resistor between BI/TOUT and TS pins is also required. The bq27530-G1 uses temperature to monitor the battery-pack environment, which is used for fuel gauging and cell protection functionality.

To minimize power consumption, the device has different power modes: NORMAL, SLEEP, SLEEP+, HIBERNATE, and BAT INSERT CHECK. The bq27530-G1 passes automatically between these modes, depending upon the occurrence of specific events, though a system processor can initiate some of these modes directly Tz 0 0 0 rg 54 314 Td (To)Tj 19.07 0 0 Td (SLEEP+,)d (SLEE52 0 Tdtion)Tee

flash 20Tj 19

DATA COMMANDS

STANDARD DATA COMMANDS

Thebq27530-G1 uses a series of 2-byte standard commands to enable system reading and writing of battery information. Each standard command has an associated command-code pair, as indicated in Table 2. Because each command consists of two bytes of data, two consecutive I^2C transmissions must be executed both to initiate the command function, and to read or write the corresponding two bytes of data. Additional details are found in the *bq27530-G1*

Control( ): 0x00/0x01

Issuing a *Control( )* command requires a subsequent 2-byte subcommand. These additional bytes specify the particular control function desired. The *Control( )* command allows the system to control specific features of the bq27530-G1 during normal operation and additional features when the device is in different access modes, as described in Table 3. Additional details are found in the *bq27530-G1 Technical Reference Manual*.

Table 3. *Control( )* Subcommands

CNTL FUNCTION	CNTL DATA	SEALED ACCESS	DESCRIPTION
CONTROL_STATUS	0x0000	Yes	Reports the status of hibernate, IT, etc.
DEVICE_TYPE	0x0001	Yes	Reports the device type (eg: bq27530)
FW_VERSION	0x0002	Yes	Reports the firmware version on the device type
HW_VERSION	0x0003	Yes	Reports the hardware version of the device type
PREV_MACWRITE	0x0007	Yes	Returns previous MAC subcommand code
CHEM_ID	0x0008	Yes	Reports the chemical identifier of the Impedance Track™ configuration
BOARD_OFFSET	0x0009	No	Forces the device to measure and store the board offset
CC_OFFSET	0x000a	No	Forces the device to measure the internal CC offset
CC_OFFSET_SAVE	0x000b	No	Forces the device to store the internal CC offset
OCV_CMD	0x000c	Yes	Request the gauge to take a OCV measurement
BAT_INSERT	0x000d	Yes	Forces the BAT_DET bit set when the *[BIE]* bit is 0
BAT_REMOVE	0x000e	Yes	Forces the BAT_DET bit clear when the *[BIE]* bit is 0
SET_HIBERNATE	0x0011	Yes	Forces CONTROL_STATUS *[HIBERNATE]* to 1
CLEAR_HIBERNATE	0x0012	Yes	Forces CONTROL_STATUS *[HIBERNATE]* to 0
SET_SLEEP+	0x0013	Yes	Forces CONTROL_STATUS *[SNOOZE]* to 1
CLEAR_SLEEP+	0x0014	Yes	Forces CONTROL_STATUS *[SNOOZE]* to 0
DIV_CUR_ENABLE	0x0017	Yes	Makes the programmed charge current to be half of what is calculated by the gauge charging algorithm.
CHG_ENABLE	0x001A	Yes	Enable charger. Charge will continue as dictated by gauge charging algorithm.
CHG_DISABLE	0x001B	Yes	Disable charger (Set $\overline{CE}$ bit of bq2416x)
GG_CHGRCTL_ENABLE	0x001C	Yes	Enables the gas gauge to control the charger while continuosly resetting the charger watchdog
GG_CHGRCTL_DISABLE	0x001D	Yes	The gas gauge stops resetting the charger watchdog
DIV_CUR_DISABLE	0x001E	Yes	Makes the programmed charge current to be same as what is calculated by the gauge charging algorithm.
DF_VERSION	0x001F	Yes	Returns the Data Flash Version
SEALED	0x0020	No	Places device in SEALED access mode
IT_ENABLE	0x0021	No	Enables the Impedance Track™ algorithm
RESET	0x0041	No	Forces a full reset of the bq27530-G1

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FUNCTIONAL DESCRIPTION

The bq27530-G1 measures the cell voltage, temperature, and current to determine battery SOC. The bq27530-G1 monitors charge and discharge activity by sensing the voltage across a small-value resistor (5 mΩ to 20 mΩ typ.) between the SRP and SRN pins and in series with the cell. By integrating charge passing through the battery, the battery's SOC is adjusted during battery charge or discharge.

The total battery capacity is found by comparing states of charge before and after applying the load with the amount of charge passed. When an application load is applied, the impedance of the cell is measured by comparing the OCV obtained from a predefined function for present SOC with the measured voltage under load. Measurements of OCV and charge integration determine chemical state of charge and chemical capacity (Qmax). The initial Qmax values are taken from a cell manufacturers' data sheet multiplied by the number of parallel cells. It is also used for the value in ***Design Capacity***. The bq27530-G1 acquires and updates the battery-impedance profile during normal battery usage. It uses this profile, along with SOC and the Qmax value, to determine *FullChargeCapacity( )* and *StateOfCharge( )*, specifically for the present load and temperature. *FullChargeCapacity( )* is reported as capacity available from a fully charged battery under the present load and temperature until *Voltage( )* reaches the ***Terminate Voltage***. *NominalAvailableCapacity( )* and *FullAvailableCapacity( )* are the uncompensated (no or light load) versions of *RemainingCapacity( )* and *FullChargeCapacity( )* respectively.

The bq27530-G1 has two flags accessed by the *Flags( )* function that warns when the battery's SOC has fallen to critical levels. When *RemainingCapacity( )* falls below the first capacity threshold, specified in ***SOC1 Set Threshold***, the *[SOC1] (State of Charge Initial)* flag is set. The flag is cleared once *RemainingCapacity( )* rises above **SOC1 Clear Threshold**.

When *Voltage( )* falls below the system shut down threshold voltage, ***SysDown Set Volt Threshold***, the *[SYSDOWN]* flag is set, serving as a final warning to shut down the system. The SOC_INT also signals. When *Voltage( )* rises above ***SysDown Clear Voltage*** and the *[SYSDOWN]* flag has already been set, the *[SYSDOWN]* flag is cleared. The SOC_INT also signals such change. All units are in mV.

When the voltage is discharged to ***Terminate Voltage***, the SOC will be set as 0.

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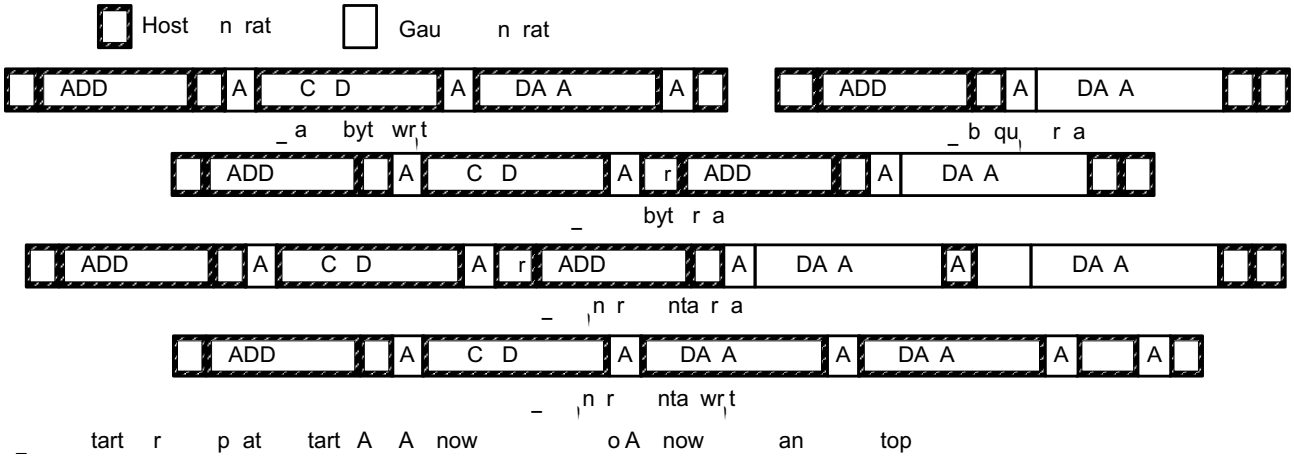
COMMUNICATIONS

I²C INTERFACE

The bq27530-G1 supports the standard I²C read, incremental read, quick read, one byte write, and incremental write functions. The 7 bit device address (ADDR) is the most significant 7 bits of the hex address and is fixed as 1010101. The first 8-bits of the I²C protocol will; therefore, be 0xAA or 0xAB for write or read, respectively.



The “quick read” returns data at the address indicated by the address pointer. The address pointer, a register internal to the I²C communication engine, will increment whenever data is acknowledged by the bq27530-G1 or the I²C master. “Quick writes” function in the same manner and are a convenient means of sending multiple bytes to consecutive command locations (such as two-byte commands that require two bytes of data)

The following command sequences are not supported:

Attempt to write a read-only address (NACK after data sent by master):

Attempt to read an address above 0x6B (NACK command):

I²C Time Out

The I²C engine will release both SDA and SCL if the I²C bus is held low for 2 seconds. If the bq27530-G1 was holding the lines, releasing them will free them for the master to drive the lines. If an external condition is holding either of the lines low, the I²C engine will enter the low power sleep mode.

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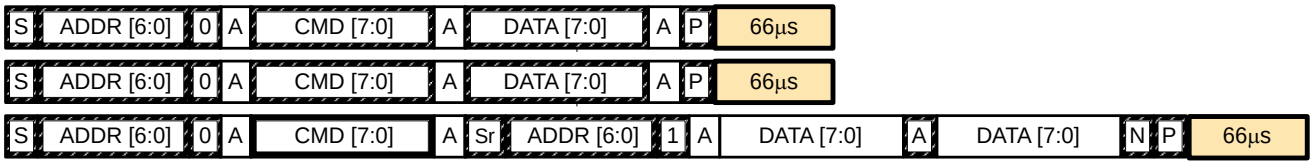
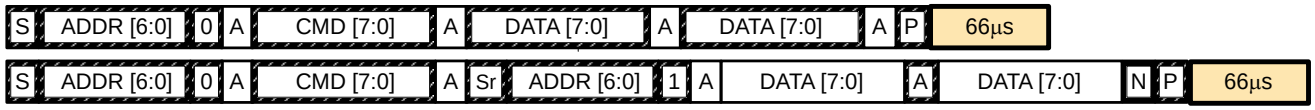
I²C Command Waiting Time

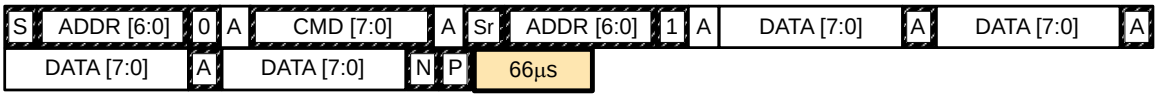
To ensure proper operation at 400 kHz, a $t_{(BUF)}$ ≥ 66 µs bus free waiting time should be inserted between all packets addressed to the bq27530-G1 . In addition, if the SCL clock frequency (f_{SCL}) is > 100 kHz, use individual 1-byte write commands for proper data flow control. The following diagram shows the standard waiting time required between issuing the control subcommand the reading the status result. A DF_CHECKSUM subcommand requires 100mS minimum prior to reading the result. An OCV_CMD subcommand requires 1.2 seconds prior to reading the result. For read-write standard command, a minimum of 2 seconds is required to get the result updated. For read-only standard commands, there is no waiting time required, but the host should not issue all standard commands more than two times per second. Otherwise, the gauge could result in a reset issue due to the expiration of the watchdog timer.



Waiting time inserted between two 1-byte write packets for a subcommand and reading results
(required for 100 kHz < f_{SCL} ≤ 400 kHz)



Waiting time inserted between incremental 2-byte write packet for a subcommand and reading results
(acceptable for f_{SCL} ≤ 100 kHz)



Waiting time inserted after incremental read

I²C Clock Stretching

A clock stretch can occur during all modes of fuel gauge operation. In SLEEP and HIBERNATE modes, a short clock stretch will occur on all I²C traffic as the device must wake-up to process the packet. In the other modes (BAT INSERT CHECK , NORMAL, SLEEP+) clock stretching will only occur for packets addressed for the fuel gauge. The majority of clock stretch periods are small as the I²C interface performs normal data flow control. However, less frequent yet more significant clock stretch periods may occur as blocks of Data Flash are updated. The following table summarizes the approximate clock stretch duration for various fuel gauge operating conditions.

Gauging Mode	Operating Condition / Comment	Approximate Duration
SLEEP HIBERNATE	Clock stretch occurs at the beginning of all traffic as the device wakes up.	≤ 4 ms
BAT INSERT CHECK NORMAL SLEEP+	Clock stretch occurs within the packet for flow control. (after a start bit, ACK or first data bit)	≤ 4 ms
	Normal Ra table Data Flash updates.	24 ms
	Data Flash block writes.	72 ms
	Restored Data Flash block write after loss of power.	116 ms
	End of discharge Ra table Data Flash update.	144 ms

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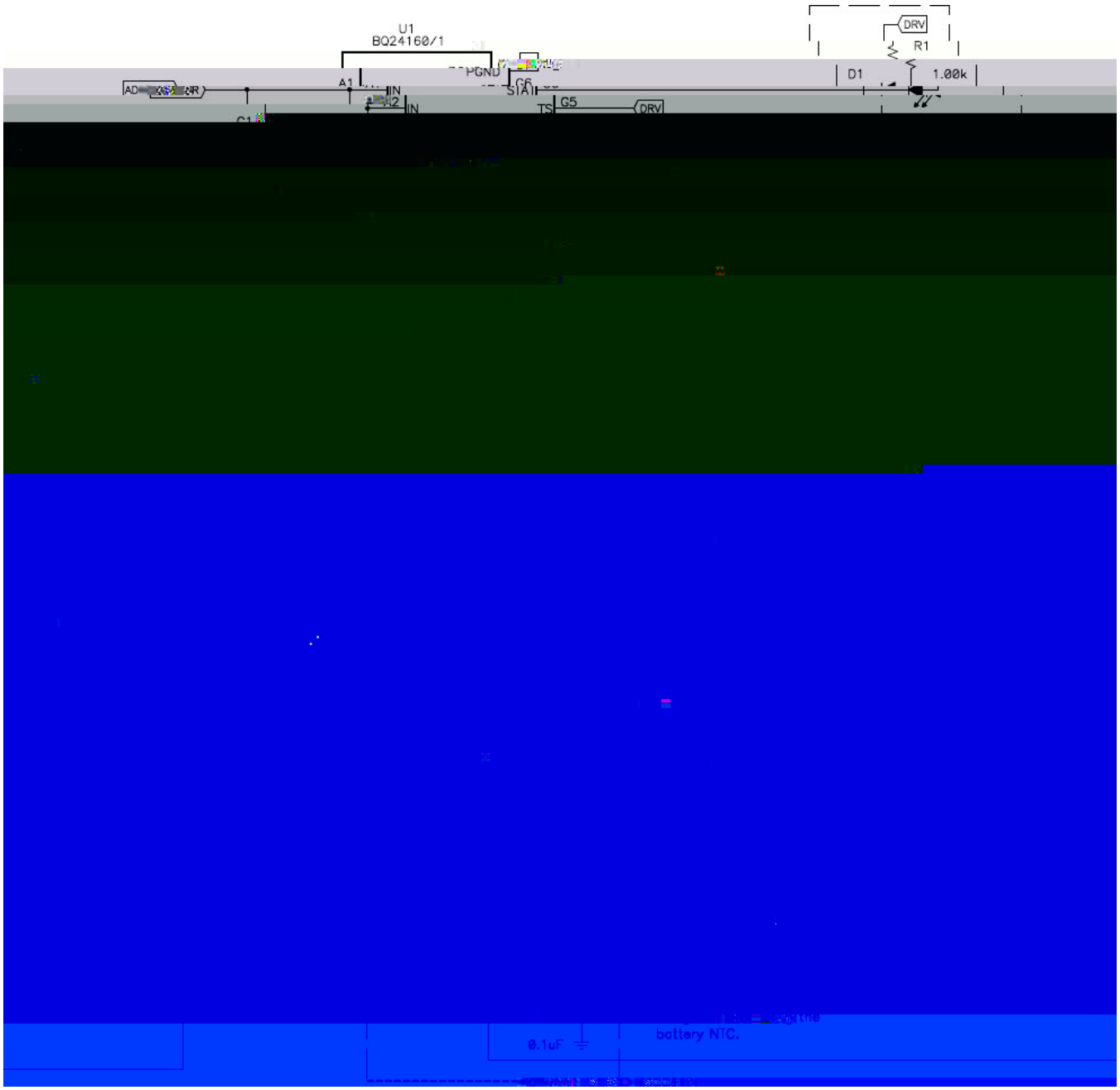
REFERENCE SCHEMATICS

SCHEMATIC



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